

140 COMMERCE DRIVE MONTGOMERYVILLE, PA 18936-1013 PHONE: (215) 631-9840 FAX: (215) 631-9855

# **MSC1400M**

### RF & MICROWAVE TRANSISTORS AVIONICS APPLICATIONS

### Features

- 1025-1150 MHz
- 25:1 VSWR CAPABILITY
- P<sub>OUT</sub> = 400 WATTS
- $G_P = 6.5 \text{ dB MINIMUM}$
- GOLD METALLIZATION
- INPUT/OUTPUT MATCHING
- COMMON BASE CONFIGURATION

### DESCRIPTION:

The MSC1400M is a high power pulsed transistor specifically designed for IFF avionics applications. It is designed for operation under short pulse width and low duty cycle pulse conditions and is capable of withstanding a minimum 25:1 load mismatch at rated RF conditions. Internal impedance matching and gold metallization ensure high product reliability and consistency.





### ABSOLUTE MAXIMUM RATINGS (Tcase = 25°C)

Symbol	Parameter	Value	Unit
PDISS	Power Dissipation	1000	W
Ι <sub>c</sub>	Device Current	28	Α
V <sub>cc</sub>	Collector - Base Voltage	55	V
TJ	Junction Temperature	+250	°C
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C

#### Thermal Data

R <sub>TH(J-C)</sub> Inermal Resistance Junction-case 0.12 °C/W
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## ELECTRICAL SPECIFICATIONS (Tcase = 25°C)

#### STATIC

Symbol	Tost Conditions		Value			Unit	
	Test conditions		Γ	Min.	Тур.	Max.	Unit
BV <sub>CBO</sub>	l <sub>c</sub> = 15mA	I <sub>E</sub> = 0mA		65			V
BV <sub>EBO</sub>	l <sub>E</sub> = 1mA	I <sub>C</sub> = 0mA		3.5			V
BV <sub>CER</sub>	I <sub>C</sub> = 50mA	R <sub>BE</sub> = 10Ω		65			V
I <sub>CES</sub>	V <sub>CB</sub> = 50V					35	mA
HFE	$V_{CE} = 5V$	$I_{C} = 1A$		15		120	

### DYNAMIC

Symbol	Test Conditions		Val	Unit	
Symbol			າ. Ty	p. Max.	Unit
Pout	$f = 1025-1150 \text{ MHz}$ $P_{IN} = 90 \text{ W}$ $V_{CC} = 50 \text{ V}$	40	0 45	50	w
ηc	$f = 1025-1150 \text{ MHz}$ $P_{IN} = 90 \text{ W}$ $V_{CC} = 50 \text{ V}$	40			%
G <sub>P</sub>	$f = 1025-1150 \text{ MHz}$ $P_{IN} = 90 \text{ W}$ $V_{CC} = 50 \text{ V}$	6.	5		dB
Conditions	Pulse Width = $10\mu$ S Duty Cycle = 1%				



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**TEST CIRCUIT** 

Ref.: Dwg. No. C125363



All dimensions are in inches.



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### PACKAGE MECHANICAL DATA

### PACKAGE STYLE M216





	MINIMUM	MAXIMUM		MINIMUM	MAXIMUM		
	INCHES/MM	INCHES/MM		INCHES/MM	INCHES/MM		
Α	.140,	/3,56	J	.700/17,78			
В	.110/2,80		K	.386/9,80			
С	.110/	/2,80	L	.900/22.86			
D	.395/10,03	.407/10,34	М	.120/3,05			
E	.193/4,90		Ν	.500/12,70			
F		.230/5,84	0	.050/1,27			
G	.003/0,08	.006/0,15	Ρ		.170/4,32		
Н	.118/3,00	.131/3,33	Q	.062/1,58			
	.063,	/1,60					

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